



#### Welcome to E-XFL.COM

#### What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

#### Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

#### Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	32MHz
Connectivity	I <sup>2</sup> C, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, LCD, POR, PWM, WDT
Number of I/O	36
Program Memory Size	28KB (16K x 14)
Program Memory Type	FLASH
EEPROM Size	256 x 8
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 14x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Through Hole
Package / Case	40-DIP (0.600", 15.24mm)
Supplier Device Package	40-PDIP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16lf1939-e-p

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

### **Peripheral Features (Continued):**

- · Master Synchronous Serial Port (MSSP) with SPI and I<sup>2</sup>C<sup>™</sup> with:
  - 7-bit address masking
  - SMBus/PMBus<sup>™</sup> compatibility
  - Auto-wake-up on start
- · Enhanced Universal Synchronous Asynchronous Receiver Transmitter (EUSART):
  - RS-232, RS-485 and LIN compatible
  - Auto-Baud Detect
- SR Latch (555 Timer):
  - Multiple Set/Reset input options
  - Emulates 555 Timer applications
- PIC16(L)F193X/194X FAMILY TYPES CD (Com/Seg/Total Data Sheet Index Program Memory MSSP (I<sup>2</sup>C<sup>TM</sup>/SPI) 0-bit ADC (ch) Cap Sense (ch) Data EEPROM Flash (words) Comparators Data SRAM Timers (8/16-bit) Debug<sup>(1)</sup> EUSART (bytes) I/0's<sup>(2)</sup> (bytes) ECCP ССР ХГР Device PIC16(L)F1933 (1)4096 256 256 25 11 8 2 4/1 1 3 2 4/16/60<sup>(3)</sup> I/H/E Y 1 2 PIC16(L)F1934 4096 256 36 14 16 2 4/1 1 3 4/24/96 I/H/E Υ (2) 256 1 PIC16(L)F1936 8192 256 512 25 11 8 2 4/1 1 1 3 2 4/16/60(3) I/H/E Y (2)PIC16(L)F1937 14 16 1 3 2 4/24/96 I/H/E Y 8192 256 512 36 2 4/1 1 (2)PIC16(L)F1938 16384 256 1024 25 11 8 2 4/1 1 1 3 2 4/16/60<sup>(3)</sup> I/H/E Y (3)PIC16(L)F1939 16384 256 1024 36 14 16 2 4/1 1 3 2 4/24/96 I/H/E Y (3) 1 PIC16(L)F1946 (4)8192 256 512 54 17 17 3 4/1 2 2 3 2 4/46/184 Т Y 1024 Y PIC16(L)F1947 (4) 16384 256 54 17 17 3 4/1 2 2 3 2 4/46/184 Т

Debugging Methods: (I) – Integrated On-Chip; (H) – using Debug Header; (E) – using Emulation Header. Note 1:

2: One pin is input-only.

3: COM3 and SEG15 share the same physical pin, therefore SEG15 is not available when using 1/4 multiplex displays.

Data Sheet Index: (Unshaded devices are described in this document.)

- 1: DS41575 PIC16(L)F1933 Data Sheet, 28-Pin Flash, 8-bit Microcontrollers.
- 2: DS41364 PIC16(L)F1934/6/7 Data Sheet, 28/40/44-Pin Flash, 8-bit Microcontrollers.
- PIC16(L)F1938/9 Data Sheet, 28/40/44-Pin Flash, 8-bit Microcontrollers. 3: DS41574
- PIC16(L)F1946/1947 Data Sheet, 64-Pin Flash, 8-bit Microcontrollers. 4: DS41414

For other small form-factor package availability and marking information, please visit Note: http://www.microchip.com/packaging or contact your local sales office.

- · 2 Comparators:
  - Rail-to-rail inputs/outputs
  - Power mode control
  - Software enable hysteresis
- Voltage Reference module:
  - Fixed Voltage Reference (FVR) with 1.024V, 2.048V and 4.096V output levels
  - 5-bit rail-to-rail resistive DAC with positive and negative reference selection

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on POR, BOR	Value on all other Resets
Bank 5											
280h <sup>(2)</sup>	INDF0		this location ical register)	uses contents	s of FSR0H/F	SR0L to addre	ess data mei	mory		****	****
281h <sup>(2)</sup>	INDF1		this location ical register)	uses contents	s of FSR1H/F	SR1L to addre	ess data mei	mory		****	****
282h <sup>(2)</sup>	PCL	Program Co	ounter (PC) L	east Significa	int Byte					0000 0000	0000 0000
283h <sup>(2)</sup>	STATUS	_	_	_	TO	PD	Z	DC	С	1 1000	q quuu
284h <sup>(2)</sup>	FSR0L	Indirect Dat	a Memory Ac	Idress 0 Low	Pointer			•	•	0000 0000	uuuu uuuu
285h <sup>(2)</sup>	FSR0H	Indirect Dat	a Memory Ac	ldress 0 High	Pointer					0000 0000	0000 0000
286h <sup>(2)</sup>	FSR1L	Indirect Dat	a Memory Ac	Idress 1 Low	Pointer					0000 0000	uuuu uuuu
287h <sup>(2)</sup>	FSR1H	Indirect Dat	a Memory Ac	ldress 1 High	Pointer					0000 0000	0000 0000
288h <sup>(2)</sup>	BSR	_	_	—		E	BSR<4:0>			0 0000	0 0000
289h <sup>(2)</sup>	WREG	Working Re	gister							0000 0000	uuuu uuuu
28Ah <sup>(1, 2)</sup>	PCLATH	_	Write Buffer	for the upper	7 bits of the F	rogram Coun	iter			-000 0000	-000 0000
28Bh <sup>(2)</sup>	INTCON	GIE	PEIE	TMR0IE	INTE	IOCIE	TMR0IF	INTF	IOCIF	0000 0000	0000 0000
28Ch	—	Unimpleme	nted							_	_
28Dh	_	Unimplemented								_	_
28Eh	_	Unimpleme	Unimplemented								_
28Fh	_	Unimpleme	nted							_	_
290h	_	Unimpleme	nted							_	_
291h	CCPR1L	Capture/Co	mpare/PWM	Register 1 (L	SB)					XXXX XXXX	uuuu uuuu
292h	CCPR1H	Capture/Co	mpare/PWM	Register 1 (M	ISB)					XXXX XXXX	uuuu uuuu
293h	CCP1CON	P1M	<1:0>	DC1E	8<1:0>		CCP1M	<3:0>		0000 0000	0000 0000
294h	PWM1CON	P1RSEN			F	21DC<6:0>				0000 0000	0000 0000
295h	CCP1AS	CCP1ASE	CCP1AS2	CCP1AS1	CCP1AS0	PSS1A	C<1:0>	PSS1B	D<1:0>	0000 0000	0000 0000
296h	PSTR1CON	_	_	_	STR1SYNC	STR1D	STR1C	STR1B	STR1A	0 0001	0 0001
297h	_	Unimpleme	nted							_	_
298h	CCPR2L	Capture/Co	mpare/PWM	Register 2 (L	SB)					XXXX XXXX	uuuu uuuu
299h	CCPR2H	Capture/Co	mpare/PWM	Register 2 (N	ISB)					XXXX XXXX	uuuu uuuu
29Ah	CCP2CON	P2M	<1:0>	DC2E	3<1:0>		CCP2M	<3:0>		0000 0000	0000 0000
29Bh	PWM2CON	P2RSEN			F	2DC<6:0>				0000 0000	0000 0000
29Ch	CCP2AS	CCP2ASE	CCP2AS2	CCP2AS1	CCP2AS0	PSS2A	C<1:0>	PSS2E	D<1:0>	0000 0000	0000 0000
29Dh	PSTR2CON	_	_	—	STR2SYNC	STR2D	STR2C	STR2B	STR2A	0 0001	0 0001
29Eh	CCPTMRS0	C4TSEL1	C4TSEL0	C3TSEL1	C3TSEL0	C2TSEL1	C2TSEL0	C1TSEL1	C1TSEL0	0000 0000	0000 0000
29Fh	CCPTMRS1	1		<u> </u>		<u> </u>			L<1:0>	00	00

#### SPECIAL FUNCTION REGISTER SUMMARY (CONTINUED) TABLE 3-10.

Legend: x = unknown, u = unchanged, q = value depends on condition, - = unimplemented, read as '0', r = reserved. Shaded locations are unimplemented, read as '0'.

Note 1: The upper byte of the program counter is not directly accessible. PCLATH is a holding register for the PC<14:8>, whose contents are transferred to the upper byte of the program counter.

These registers can be addressed from any bank. 2:

These registers/bits are not implemented on PIC16(L)F1938 devices, read as '0'. 3:

4: Unimplemented, read as '1'.

### 3.5 Stack

All devices have a 16-level x 15-bit wide hardware stack (refer to Figure 3-1). The stack space is not part of either program or data space. The PC is PUSHed onto the stack when CALL or CALLW instructions are executed or an interrupt causes a branch. The stack is POPed in the event of a RETURN, RETLW or a RETFIE instruction execution. PCLATH is not affected by a PUSH or POP operation.

The stack operates as a circular buffer if the STVREN bit is programmed to '0' (Configuration Words). This means that after the stack has been PUSHed sixteen times, the seventeenth PUSH overwrites the value that was stored from the first PUSH. The eighteenth PUSH overwrites the second PUSH (and so on). The STKOVF and STKUNF flag bits will be set on an Overflow/Underflow, regardless of whether the Reset is enabled.

Note 1: There are no instructions/mnemonics called PUSH or POP. These are actions that occur from the execution of the CALL, CALLW, RETURN, RETLW and RETFIE instructions or the vectoring to an interrupt address.

#### 3.5.1 ACCESSING THE STACK

The stack is available through the TOSH, TOSL and STKPTR registers. STKPTR is the current value of the Stack Pointer. TOSH:TOSL register pair points to the TOP of the stack. Both registers are read/writable. TOS is split into TOSH and TOSL due to the 15-bit size of the PC. To access the stack, adjust the value of STKPTR, which will position TOSH:TOSL, then read/write to TOSH:TOSL. STKPTR is 5 bits to allow detection of overflow and underflow.

Note:	Care should be taken when modifying the
	STKPTR while interrupts are enabled.

During normal program operation, CALL, CALLW and Interrupts will increment STKPTR while RETLW, RETURN, and RETFIE will decrement STKPTR. At any time STKPTR can be inspected to see how much stack is left. The STKPTR always points at the currently used place on the stack. Therefore, a CALL or CALLW will increment the STKPTR and then write the PC, and a return will unload the PC and then decrement the STK-PTR.

Reference Figure 3-4 through Figure 3-7 for examples of accessing the stack.

#### FIGURE 3-4: ACCESSING THE STACK EXAMPLE 1

TOSH:TOSL 0x0F	STKPTR = 0x1F Stack Reset Disabled (STVREN = 0)
0x0E	N
0x0D	
0x0C	
0x0B	
0x0A	Initial Charly Configuration
0x09	Initial Stack Configuration:
0x08	After Reset, the stack is empty. The empty stack is initialized so the Stack
0x07	Pointer is pointing at 0x1F. If the Stack Overflow/Underflow Reset is enabled, the
0x06	TOSH/TOSL registers will return '0'. If the Stack Overflow/Underflow Reset is
0x05	disabled, the TOSH/TOSL registers will
0x04	return the contents of stack address 0x0F.
0x03	
0x02	
0x01	
0x00	
TOSH:TOSL 0x1F	0x0000 STKPTR = 0x1F Stack Reset Enabled (STVREN = 1)

FIGURE 6-3:	RESET START-UP SEQUENCE
VDD	
Internal POR	
Power Up Timer	
MCLR	
Internal RESET	
internal RESET	
	Oscillator Modes – – – – – – – – – – – – – – – – – – –
External Crystal	◀ Tost
Oscillator Start Up Timer	
Oscillator	
Fosc	
Internal Oscillator	
Oscillator	
Fosc	
External Clock (EC)	
CLKIN	
Fosc	

### 11.0 DATA EEPROM AND FLASH PROGRAM MEMORY CONTROL

The Data EEPROM and Flash program memory are readable and writable during normal operation (full VDD range). These memories are not directly mapped in the register file space. Instead, they are indirectly addressed through the Special Function Registers (SFRs). There are six SFRs used to access these memories:

- EECON1
- EECON2
- EEDATL
- EEDATH
- EEADRL
- EEADRH

When interfacing the data memory block, EEDATL holds the 8-bit data for read/write, and EEADRL holds the address of the EEDATL location being accessed. These devices have 256 bytes of data EEPROM with an address range from 0h to 0FFh.

When accessing the program memory block, the EED-ATH:EEDATL register pair forms a 2-byte word that holds the 14-bit data for read/write, and the EEADRL and EEADRH registers form a 2-byte word that holds the 15-bit address of the program memory location being read.

The EEPROM data memory allows byte read and write. An EEPROM byte write automatically erases the location and writes the new data (erase before write).

The write time is controlled by an on-chip timer. The write/erase voltages are generated by an on-chip charge pump rated to operate over the voltage range of the device for byte or word operations.

Depending on the setting of the Flash Program Memory Self Write Enable bits WRT<1:0> of the Configuration Words, the device may or may not be able to write certain blocks of the program memory. However, reads from the program memory are always allowed.

When the device is code-protected, the device programmer can no longer access data or program memory. When code-protected, the CPU may continue to read and write the data EEPROM memory and Flash program memory.

### 11.1 EEADRL and EEADRH Registers

The EEADRH:EEADRL register pair can address up to a maximum of 256 bytes of data EEPROM or up to a maximum of 32K words of program memory.

When selecting a program address value, the MSB of the address is written to the EEADRH register and the LSB is written to the EEADRL register. When selecting a EEPROM address value, only the LSB of the address is written to the EEADRL register.

#### 11.1.1 EECON1 AND EECON2 REGISTERS

EECON1 is the control register for EE memory accesses.

Control bit EEPGD determines if the access will be a program or data memory access. When clear, any subsequent operations will operate on the EEPROM memory. When set, any subsequent operations will operate on the program memory. On Reset, EEPROM is selected by default.

Control bits RD and WR initiate read and write, respectively. These bits cannot be cleared, only set, in software. They are cleared in hardware at completion of the read or write operation. The inability to clear the WR bit in software prevents the accidental, premature termination of a write operation.

The WREN bit, when set, will allow a write operation to occur. On power-up, the WREN bit is clear. The WRERR bit is set when a write operation is interrupted by a Reset during normal operation. In these situations, following Reset, the user can check the WRERR bit and execute the appropriate error handling routine.

Interrupt flag bit EEIF of the PIR2 register is set when write is complete. It must be cleared in the software.

Reading EECON2 will read all '0's. The EECON2 register is used exclusively in the data EEPROM write sequence. To enable writes, a specific pattern must be written to EECON2.

#### 11.3.2 ERASING FLASH PROGRAM MEMORY

While executing code, program memory can only be erased by rows. To erase a row:

- 1. Load the EEADRH:EEADRL register pair with the address of new row to be erased.
- 2. Clear the CFGS bit of the EECON1 register.
- 3. Set the EEPGD, FREE, and WREN bits of the EECON1 register.
- 4. Write 55h, then AAh, to EECON2 (Flash programming unlock sequence).
- 5. Set control bit WR of the EECON1 register to begin the erase operation.
- 6. Poll the FREE bit in the EECON1 register to determine when the row erase has completed.

#### See Example 11-4.

After the "BSF EECON1, WR" instruction, the processor requires two cycles to set up the erase operation. The user must place two NOP instructions after the WR bit is set. The processor will halt internal operations for the typical 2 ms erase time. This is not Sleep mode as the clocks and peripherals will continue to run. After the erase cycle, the processor will resume operation with the third instruction after the EECON1 write instruction.

### 11.3.3 WRITING TO FLASH PROGRAM MEMORY

Program memory is programmed using the following steps:

- 1. Load the starting address of the word(s) to be programmed.
- 2. Load the write latches with data.
- 3. Initiate a programming operation.
- 4. Repeat steps 1 through 3 until all data is written.

Before writing to program memory, the word(s) to be written must be erased or previously unwritten. Program memory can only be erased one row at a time. No automatic erase occurs upon the initiation of the write.

Program memory can be written one or more words at a time. The maximum number of words written at one time is equal to the number of write latches. See Figure 11-2 (block writes to program memory with 8 write latches) for more details. The write latches are aligned to the address boundary defined by EEADRL as shown in Table 11-1. Write operations do not cross these boundaries. At the completion of a program memory write operation, the write latches are reset to contain 0x3FFF. The following steps should be completed to load the write latches and program a block of program memory. These steps are divided into two parts. First, all write latches are loaded with data except for the last program memory location. Then, the last write latch is loaded and the programming sequence is initiated. A special unlock sequence is required to load a write latch with data or initiate a Flash programming operation. This unlock sequence should not be interrupted.

- 1. Set the EEPGD and WREN bits of the EECON1 register.
- 2. Clear the CFGS bit of the EECON1 register.
- Set the LWLO bit of the EECON1 register. When the LWLO bit of the EECON1 register is '1', the write sequence will only load the write latches and will not initiate the write to Flash program memory.
- 4. Load the EEADRH:EEADRL register pair with the address of the location to be written.
- 5. Load the EEDATH:EEDATL register pair with the program memory data to be written.
- Write 55h, then AAh, to EECON2, then set the WR bit of the EECON1 register (Flash programming unlock sequence). The write latch is now loaded.
- 7. Increment the EEADRH:EEADRL register pair to point to the next location.
- 8. Repeat steps 5 through 7 until all but the last write latch has been loaded.
- Clear the LWLO bit of the EECON1 register. When the LWLO bit of the EECON1 register is '0', the write sequence will initiate the write to Flash program memory.
- 10. Load the EEDATH:EEDATL register pair with the program memory data to be written.
- 11. Write 55h, then AAh, to EECON2, then set the WR bit of the EECON1 register (Flash programming unlock sequence). The entire latch block is now written to Flash program memory.

It is not necessary to load the entire write latch block with user program data. However, the entire write latch block will be written to program memory.

An example of the complete write sequence for eight words is shown in Example 11-5. The initial address is loaded into the EEADRH:EEADRL register pair; the eight words of data are loaded using indirect addressing.

Note: The code sequence provided in Example 11-5 must be repeated multiple times to fully program an erased program memory row.

### 12.6 Register Definitions: PORTB Control

#### REGISTER 12-6: PORTB: PORTB REGISTER

R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	
RB7	RB6	RB5	RB4	RB3	RB2	RB1	RB0	
bit 7							bit 0	
Legend:								
R = Readable I	oit	W = Writable	bit	U = Unimplemented bit, read as '0'				
u = Bit is uncha	anged	x = Bit is unkr	nown	-n/n = Value at POR and BOR/Value at all other Re			ther Resets	
'1' = Bit is set		'0' = Bit is clea	ared					

bit 7-0 **RB<7:0>**: PORTB I/O Pin bit 1 = Port pin is > VIH 0 = Port pin is < VIL

#### REGISTER 12-7: TRISB: PORTB TRI-STATE REGISTER

| R/W-1/1 |
|---------|---------|---------|---------|---------|---------|---------|---------|
| TRISB7  | TRISB6  | TRISB5  | TRISB4  | TRISB3  | TRISB2  | TRISB1  | TRISB0  |
| bit 7   |         |         |         |         |         |         | bit 0   |

Legend:		
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

bit 7-0 **TRISB<7:0>:** PORTB Tri-State Control bits 1 = PORTB pin configured as an input (tri-stated)

0 = PORTB pin configured as an output

#### REGISTER 12-8: LATB: PORTB DATA LATCH REGISTER

| R/W-x/u |
|---------|---------|---------|---------|---------|---------|---------|---------|
| LATB7   | LATB6   | LATB5   | LATB4   | LATB3   | LATB2   | LATB1   | LATB0   |
| bit 7   |         |         |         |         |         |         | bit 0   |

Legend:		
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

bit 7-0 LATB<7:0>: PORTB Output Latch Value bits<sup>(1)</sup>

**Note 1:** Writes to PORTB are actually written to corresponding LATB register. Reads from PORTB register is return of actual I/O pin values.

### 12.12 Register Definitions: PORTE Control

### REGISTER 12-18: PORTE: PORTE REGISTER

U-0	U-0	U-0	U-0	R-x/u	R/W-x/u	R/W-x/u	R/W-x/u
—	_	—	_	RE3	RE2 <sup>(1)</sup>	RE1 <sup>(1)</sup>	RE0 <sup>(1)</sup>
bit 7							bit 0
Legend:							
R = Readable b	bit	W = Writable b	oit	U = Unimplemented bit, read as '0'			
u = Bit is unchanged x = Bit is unknown -n/n = Value at POR and BOR/Value at all			R/Value at all o	ther Resets			
'1' = Bit is set		'0' = Bit is clea	ared				

bit 7-4 Unimplemented: Read as '0' bit 3-0 RE<3:0>: PORTE I/O Pin bits<sup>(1)</sup> 1 = Port pin is > VIH 0 = Port pin is < VIL

Note 1: RE<2:0> are not implemented on the PIC16(L)F1938. Read as '0'.

### REGISTER 12-19: TRISE: PORTE TRI-STATE REGISTER

U-0	U-0	U-0	U-0	U-1 <sup>(2)</sup>	R/W-1	R/W-1	R/W-1
_	—	_	_	_	TRISE2 <sup>(1)</sup>	TRISE1 <sup>(1)</sup>	TRISE0 <sup>(1)</sup>
bit 7							bit 0

Legend:		
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

bit 3 Unimplemented: Read as '1'

bit 2-0 **TRISE<2:0>:** RE<2:0> Tri-State Control bits<sup>(1)</sup> 1 = PORTE pin configured as an input (tri-stated) 0 = PORTE pin configured as an output

**Note 1:** TRISE<2:0> are not implemented on the PIC16(L)F1938. Read as '0'.

**2:** Unimplemented, read as '1'.

NOTES:

#### 21 11 Register Definitions: Timer1 Control

REGISTER	21-1: T1CO	N: TIMER1 C		EGISTER			
R/W-0/u	R/W-0/u	R/W-0/u	R/W-0/u	R/W-0/u	R/W-0/u	U-0	R/W-0/u
TMR1	CS<1:0>	T1CKF	PS<1:0>	T1OSCEN	T1SYNC	_	TMR10N
bit 7					I		bit
Legend:							
R = Readabl	e bit	W = Writable	bit	U = Unimpler	nented bit, read	d as '0'	
u = Bit is und	changed	x = Bit is unk	nown	-n/n = Value a	at POR and BC	R/Value at al	l other Resets
'1' = Bit is se	t	'0' = Bit is cle	ared				
bit 7-6	11 = Timer1 o 10 = Timer1 o <u>If T10So</u> External <u>If T10So</u> Crystal o 01 = Timer1 o 00 = Timer1 o	clock source is <u>CEN = 0</u> : clock from T1 <u>CEN = 1</u> : pscillator on T1 clock source is clock source is	Capacitive Se pin or oscillato CKI pin (on the OSI/T1OSO p system clock instruction clo	erising Oscillator pr: e rising edge) bins (Fosc) bck (Fosc/4)	r (CPSCLK)		
bit 5-4	<b>T1CKPS&lt;1:0</b> 11 = 1:8 Pres 10 = 1:4 Pres 01 = 1:2 Pres	scale value	ut Clock Presc	ale Select bits			

bit 1	Unimplemented: Read as '0'
bit 0	TMR10N: Timer1 On bit
	1 - Enables Timer1

00 = 1:1 Prescale value

bit 3

bit 2

T1OSCEN: LP Oscillator Enable Control bit

1 = Dedicated Timer1 oscillator circuit enabled 0 = Dedicated Timer1 oscillator circuit disabled

T1SYNC: Timer1 Synchronization Control bit 1 = Do not synchronize asynchronous clock input

0 = Synchronize asynchronous clock input with system clock (Fosc)

1 = Enables Timer1 0 = Stops Timer1

Clears Timer1 gate flip-flop

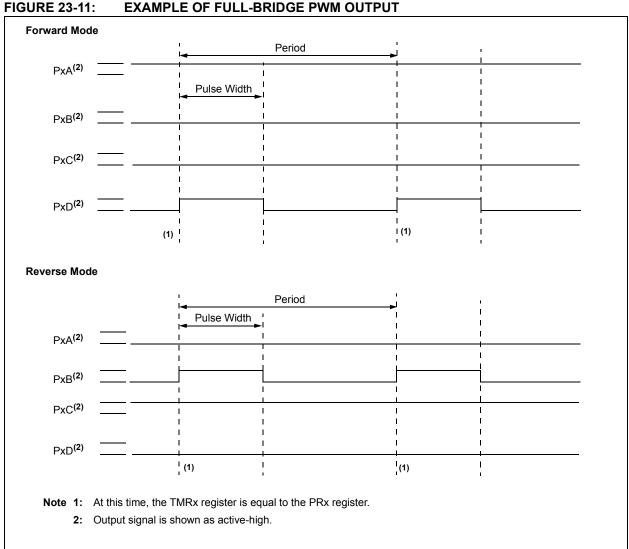


FIGURE 23-11: **EXAMPLE OF FULL-BRIDGE PWM OUTPUT** 

#### 24.6.13.1 Bus Collision During a Start Condition

During a Start condition, a bus collision occurs if:

- a) SDA or SCL are sampled low at the beginning of the Start condition (Figure 24-33).
- b) SCL is sampled low before SDA is asserted low (Figure 24-34).

During a Start condition, both the SDA and the SCL pins are monitored.

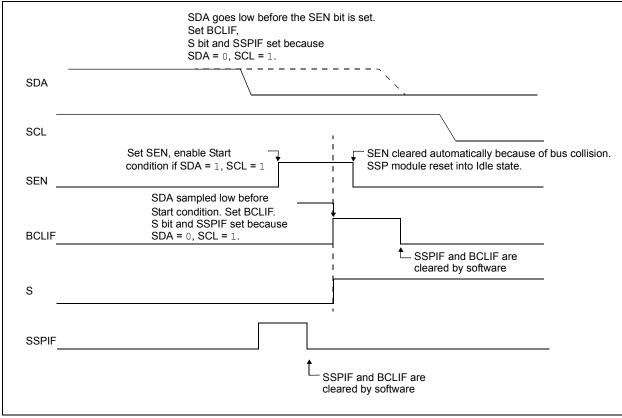
If the SDA pin is already low, or the SCL pin is already low, then all of the following occur:

- the Start condition is aborted,
- the BCLIF flag is set and
- the MSSP module is reset to its Idle state (Figure 24-33).

The Start condition begins with the SDA and SCL pins deasserted. When the SDA pin is sampled high, the Baud Rate Generator is loaded and counts down. If the SCL pin is sampled low while SDA is high, a bus collision occurs because it is assumed that another master is attempting to drive a data '1' during the Start condition.

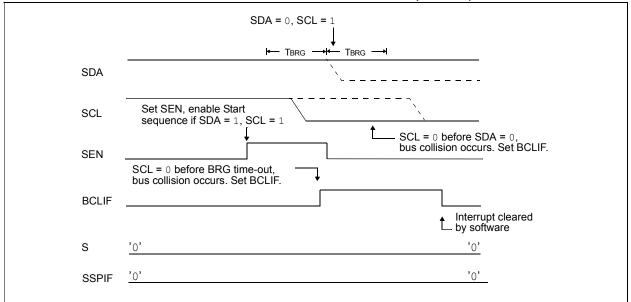
If the SDA pin is sampled low during this count, the BRG is reset and the SDA line is asserted early (Figure 24-35). If, however, a '1' is sampled on the SDA pin, the SDA pin is asserted low at the end of the BRG count. The Baud Rate Generator is then reloaded and counts down to zero; if the SCL pin is sampled as '0' during this time, a bus collision does not occur. At the end of the BRG count, the SCL pin is asserted low.

Note: The reason that bus collision is not a factor during a Start condition is that no two bus masters can assert a Start condition at the exact same time. Therefore, one master will always assert SDA before the other. This condition does not cause a bus collision because the two masters must be allowed to arbitrate the first address following the Start condition. If the address is the same, arbitration must be allowed to continue into the data portion, Repeated Start or Stop conditions.

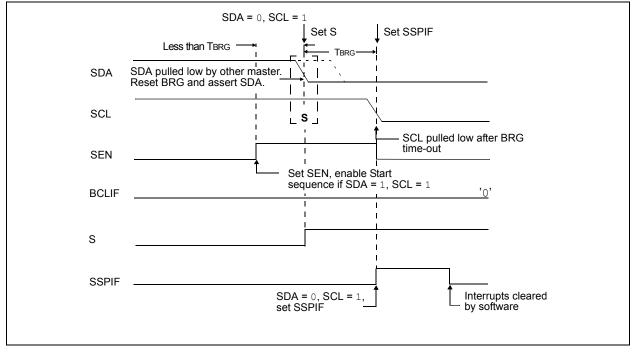


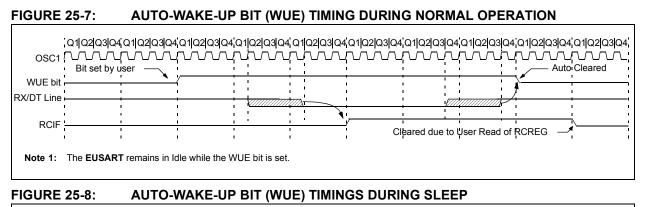
#### FIGURE 24-33: BUS COLLISION DURING START CONDITION (SDA ONLY)

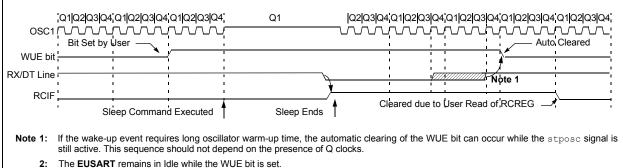




#### FIGURE 24-35: BRG RESET DUE TO SDA ARBITRATION DURING START CONDITION







### 25.6 EUSART Operation During Sleep

The EUSART will remain active during Sleep only in the Synchronous Slave mode. All other modes require the system clock and therefore cannot generate the necessary signals to run the Transmit or Receive Shift registers during Sleep.

Synchronous Slave mode uses an externally generated clock to run the Transmit and Receive Shift registers.

#### 25.6.1 SYNCHRONOUS RECEIVE DURING SLEEP

To receive during Sleep, all the following conditions must be met before entering Sleep mode:

- RCSTA and TXSTA Control registers must be configured for Synchronous Slave Reception (see Section 25.5.2.4 "Synchronous Slave Reception Set-up:").
- If interrupts are desired, set the RCIE bit of the PIE1 register and the GIE and PEIE bits of the INTCON register.
- The RCIF interrupt flag must be cleared by reading RCREG to unload any pending characters in the receive buffer.

Upon entering Sleep mode, the device will be ready to accept data and clocks on the RX/DT and TX/CK pins, respectively. When the data word has been completely clocked in by the external device, the RCIF interrupt flag bit of the PIR1 register will be set. Thereby, waking the processor from Sleep.

Upon waking from Sleep, the instruction following the SLEEP instruction will be executed. If the GIE global interrupt enable bit of the INTCON register is also set, then the Interrupt Service Routine at address 004h will be called.

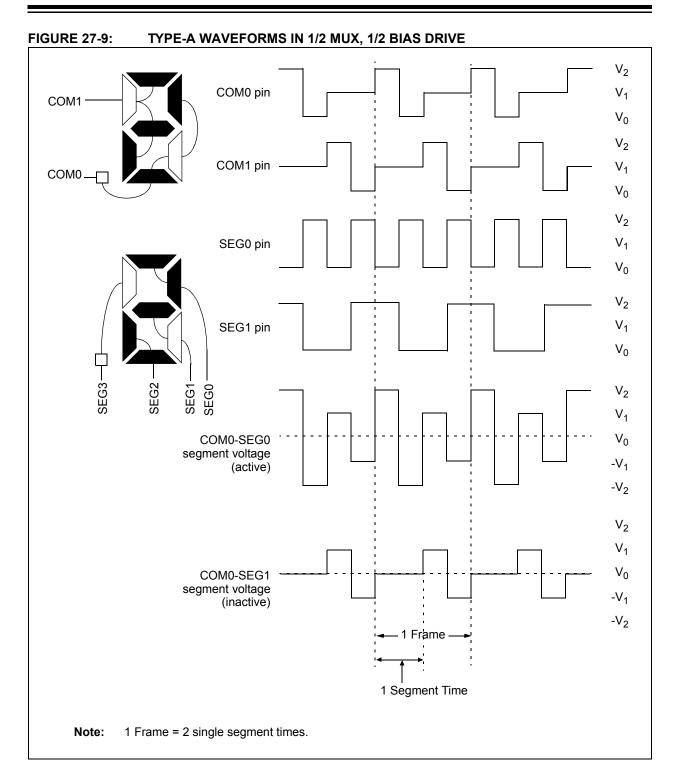
#### 25.6.2 SYNCHRONOUS TRANSMIT DURING SLEEP

To transmit during Sleep, all the following conditions must be met before entering Sleep mode:

- RCSTA and TXSTA Control registers must be configured for Synchronous Slave Transmission (see Section 25.5.2.2 "Synchronous Slave Transmission Set-up:").
- The TXIF interrupt flag must be cleared by writing the output data to the TXREG, thereby filling the TSR and transmit buffer.
- If interrupts are desired, set the TXIE bit of the PIE1 register and the PEIE bit of the INTCON register.
- Interrupt enable bits TXIE of the PIE1 register and PEIE of the INTCON register must set.

Upon entering Sleep mode, the device will be ready to accept clocks on TX/CK pin and transmit data on the RX/DT pin. When the data word in the TSR has been completely clocked out by the external device, the pending byte in the TXREG will transfer to the TSR and the TXIF flag will be set. Thereby, waking the processor from Sleep. At this point, the TXREG is available to accept another character for transmission, which will clear the TXIF flag.

Upon waking from Sleep, the instruction following the SLEEP instruction will be executed. If the Global Interrupt Enable (GIE) bit is also set then the Interrupt Service Routine at address 0004h will be called.



© 2011-2013 Microchip Technology Inc.

DS40001574C-page 343

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on Page
INTCON	GIE	PEIE	TMR0IE	INTE	IOCIE	TMR0IF	INTF	IOCIF	90
LCDCON	LCDEN	SLPEN	WERR	—	CS<	<1:0>	LMUX	<1:0>	327
LCDCST	_	_	_	_	_	l	_CDCST<2:0>	>	330
LCDDATA0	SEG7 COM0	SEG6 COM0	SEG5 COM0	SEG4 COM0	SEG3 COM0	SEG2 COM0	SEG1 COM0	SEG0 COM0	331
LCDDATA1	SEG15 COM0	SEG14 COM0	SEG13 COM0	SEG12 COM0	SEG11 COM0	SEG10 COM0	SEG9 COM0	SEG8 COM0	331
LCDDATA2	SEG23 COM0	SEG22 COM0	SEG21 COM0	SEG20 COM0	SEG19 COM0	SEG18 COM0	SEG17 COM0	SEG16 COM0	331
LCDDATA3	SEG7 COM1	SEG6 COM1	SEG5 COM1	SEG4 COM1	SEG3 COM1	SEG2 COM1	SEG1 COM1	SEG0 COM1	331
LCDDATA4	SEG15 COM1	SEG14 COM1	SEG13 COM1	SEG12 COM1	SEG11 COM1	SEG10 COM1	SEG9 COM1	SEG8 COM1	331
LCDDATA5	SEG23 COM1	SEG22 COM1	SEG21 COM1	SEG20 COM1	SEG19 COM1	SEG18 COM1	SEG17 COM1	SEG16 COM1	331
LCDDATA6	SEG7 COM2	SEG6 COM2	SEG5 COM2	SEG4 COM2	SEG3 COM2	SEG2 COM2	SEG1 COM2	SEG0 COM2	331
LCDDATA7	SEG15 COM2	SEG14 COM2	SEG13 COM2	SEG12 COM2	SEG11 COM2	SEG10 COM2	SEG9 COM2	SEG8 COM2	331
LCDDATA8	SEG23 COM2	SEG22 COM2	SEG21 COM2	SEG20 COM2	SEG19 COM2	SEG18 COM2	SEG17 COM2	SEG16 COM2	331
LCDDATA9	SEG7 COM3	SEG6 COM3	SEG5 COM3	SEG4 COM3	SEG3 COM3	SEG2 COM3	SEG1 COM3	SEG0 COM3	331
LCDDATA10	SEG15 COM3	SEG14 COM3	SEG13 COM3	SEG12 COM3	SEG11 COM3	SEG10 COM3	SEG9 COM3	SEG8 COM3	331
LCDDATA11	SEG23 COM3	SEG22 COM3	SEG21 COM3	SEG20 COM3	SEG19 COM3	SEG18 COM3	SEG17 COM3	SEG16 COM3	331
LCDPS	WFT	BIASMD	LCDA	WA		LP<	<3:0>		328
LCDREF	LCDIRE	LCDIRS	LCDIRI	—	VLCD3PE	VLCD2PE	VLCD1PE	-	329
LCDRL	LRLAF	P<1:0>	LRLBF	P<1:0>			LRLAT<2:0>		338
LCDSE0				SE	<7:0>				331
LCDSE1				SE	<15:8>				331
LCDSE2				SE<	<23:16>				331
PIE2	OSFIE	C2IE	C1IE	EEIE	BCLIE	LCDIE	_	CCP2IE	92
PIR2	OSFIF	C2IF	C1IF	EEIF	BCLIF	LCDIF	_	CCP2IF	95
T1CON	TMR1C	S<1:0>	T1CKP	S<1:0>	T1OSCEN	T1SYNC	_	TMR10N	197

Legend: — = unimplemented location, read as '0'. Shaded cells are not used by the LCD module.

RETFIE	Return from Interrupt
Syntax:	[label] RETFIE
Operands:	None
Operation:	$TOS \rightarrow PC, \\ 1 \rightarrow GIE$
Status Affected:	None
Description:	Return from Interrupt. Stack is POPed and Top-of-Stack (TOS) is loaded in the PC. Interrupts are enabled by setting Global Interrupt Enable bit, GIE (INTCON<7>). This is a 2-cycle instruction.
Words:	1
Cycles:	2
Example:	RETFIE
	After Interrupt PC = TOS GIE = 1

RETURN	Return from Subroutine		
Syntax:	[label] RETURN		
Operands:	None		
Operation:	$TOS \rightarrow PC$		
Status Affected:	None		
Description:	Return from subroutine. The stack is POPed and the top of the stack (TOS) is loaded into the program counter. This is a 2-cycle instruction.		

RETLW	Return with literal in W	RLF	Rotate Left f through Carry
Syntax:	[ <i>label</i> ] RETLW k	Syntax:	[ <i>label</i> ] RLF f,d
Operands:	$0 \le k \le 255$	Operands:	$0 \le f \le 127$ d $\in [0,1]$
Operation:	$k \rightarrow (W);$ TOS $\rightarrow$ PC	Operation:	See description below
Status Affected:	None	Status Affected:	С
Description:	The W register is loaded with the 8-bit literal 'k'. The program counter is loaded from the top of the stack (the return address). This is a 2-cycle instruction.	Description:	The contents of register 'f' are rotated one bit to the left through the Carry flag. If 'd' is '0', the result is placed in the W register. If 'd' is '1', the result is stored back in register 'f'.
Words:	1		C Register f
Cycles:	2	Words:	1
Example:	CALL TABLE;W contains table ;offset value	Cycles:	1
	<ul> <li>;W now has table value</li> </ul>	Example:	RLF REG1,0
TABLE	• • ADDWF PC ;W = offset RETLW k1 ;Begin table RETLW k2 ;		Before Instruction           REG1         =         1110         0110           C         =         0           After Instruction         REG1         =         1110         0110
	•		W = 1100 1100
	• • RETLW kn ; End of table		C = 1
	Before Instruction W = 0x07 After Instruction W = value of k8		

#### **TABLE 30-5**: RESET, WATCHDOG TIMER, OSCILLATOR START-UP TIMER, POWER-UP TIMER AND BROWN-OUT RESET

Param No.	Sym.	Characteristic	Min.	Тур†	Max.	Units	Conditions
30	ТмсL	MCLR Pulse Width (low)	2			μS	
31	TWDTLP	Low-Power Watchdog Timer Time-out Period	10	16	27	ms	VDD = 3.3V-5V 1:16 Prescaler used
32	Tost	Oscillator Start-up Timer Period <sup>(1)</sup>		1024		Tosc	
33*	TPWRT	Power-up Timer Period, PWRTE = 0	40	65	140	ms	
34*	Tioz	I/O high-impedance from MCLR Low or Watchdog Timer Reset		—	2.0	μS	
35	VBOR	Brown-out Reset Voltage <sup>(2)</sup>	2.55 1.80	2.7 1.9	2.85 2.11	V V	BORV = 0 BORV = 1
36*	VHYST	Brown-out Reset Hysteresis	20	35	60	mV	-40°C to +85°C
37*	TBORDC	Brown-out Reset DC Response Time	1	3	35	μS	$V D D \leq V B O R$

These parameters are characterized but not tested.

Data in "Typ" column is at 3.0V, 25°C unless otherwise stated. These parameters are for design guidance t only and are not tested.

Note 1: By design, the Oscillator Start-up Timer (OST) counts the first 1024 cycles, independent of frequency.

2: To ensure these voltage tolerances, VDD and VSS must be capacitively decoupled as close to the device as possible. 0.1  $\mu$ F and 0.01  $\mu$ F values in parallel are recommended.

#### **FIGURE 30-10:** TIMER0 AND TIMER1 EXTERNAL CLOCK TIMINGS

